

**Amendments to the Specification:**

Please replace paragraph [035] that spans pages 9-10 of the current specification with the following new paragraph:

[035] FIG. 3 is the cross-sectional view a substrate-triggered bipolar device 300 consistent with one embodiment of the present invention. Referring to FIG. 3, bipolar device 300 includes a substrate 302. Substrate 302 includes a plurality of N-wells 304, 306, and 308, and a P-well 310, wherein N-well 304 is formed deep in substrate 302 and isolates substrate 302 from N-wells 306 and 308 and P-well 310. P-well 310 is formed adjacent to N-well 306, and N-well 308 is formed adjacent to P-well 310. Also formed in substrate 302 are a plurality of diffusion regions, including N<sup>+</sup> regions 312, 314, and 316, and P<sup>+</sup> regions 318 and 320, wherein N<sup>+</sup> region 312 is formed in N-well 306, N<sup>+</sup> region 314 is formed in P-well 310, N<sup>+</sup> region 316 is formed in N-well 308, and P<sup>+</sup> region 320 is formed in P-well 310. P<sup>+</sup> region 318 is formed in both N-well 306 and P-well 310, i.e., a portion of P<sup>+</sup> region 318 is formed in N-well 306, and another portion of P<sup>+</sup> region 318 is formed in P-well 310. Hereinafter, when a diffusion region is described as having one portion formed in a first well and another portion formed in a second well, the diffusion region is described as having been formed in both the first well and the second well.